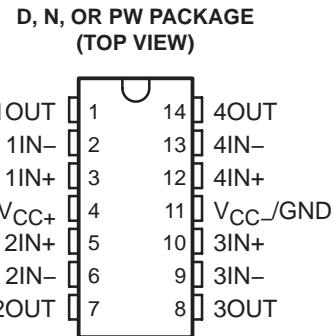


TL3474, TL3474A HIGH-SLEW-RATE, SINGLE-SUPPLY OPERATIONAL AMPLIFIERS

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- Low Offset . . . 3 mV (Max) for A-Grade
- Wide Gain-Bandwidth Product . . . 4 MHz
- High Slew Rate . . . 13 V/ μ s
- Fast Settling Time . . . 1.1 μ s to 0.1%
- Wide-Range Single-Supply Operation . . . 4 V to 36 V
- Wide Input Common-Mode Range Includes Ground (V_{CC-})
- Low Total Harmonic Distortion . . . 0.02%
- Large-Capacitance Drive Capability . . . 10,000 pF
- Output Short-Circuit Protection
- Alternative to MC33074/A and MC34074/A



description/ordering information

ORDERING INFORMATION

T_A	V_{IOmax} AT 25°C	PACKAGE[†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	A-grade: 3 mV	PDIP (N)	Tube of 25	TL3474ACN	TL3474ACN
		SOIC (D)	Tube of 50	TL3474ACD	
		TSSOP (PW)	Reel of 2500	TL3474ACDR	TL3474A
		TSSOP (PW)	Tube of 90	TL3474ACPW	
	Standard grade: 10 mV	TSSOP (PW)	Reel of 2000	TL3474ACPWR	T3474A
		PDIP (N)	Tube of 25	TL3474CN	TL3474CN
		SOIC (D)	Tube of 50	TL3474CD	
		TSSOP (PW)	Reel of 2500	TL3474CDR	TL3474C
		TSSOP (PW)	Tube of 90	TL3474CPW	
-40°C to 105°C	A-grade: 3 mV	TSSOP (PW)	Reel of 2000	TL3474CPWR	TL3474
		PDIP (N)	Tube of 25	TL3474AIN	Z3474A
		SOIC (D)	Tube of 50	TL3474AID	
		TSSOP (PW)	Reel of 2500	TL3474AIDR	TL3474AI
	Standard grade: 10 mV	TSSOP (PW)	Tube of 90	TL3474AIPW	Z3474A
		PDIP (N)	Reel of 2000	TL3474AIPWR	
		SOIC (D)	Tube of 25	TL3474IN	TL3474IN
		TSSOP (PW)	Tube of 50	TL3474ID	
		TSSOP (PW)	Reel of 2500	TL3474IDR	TL3474I

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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**TEXAS
INSTRUMENTS**

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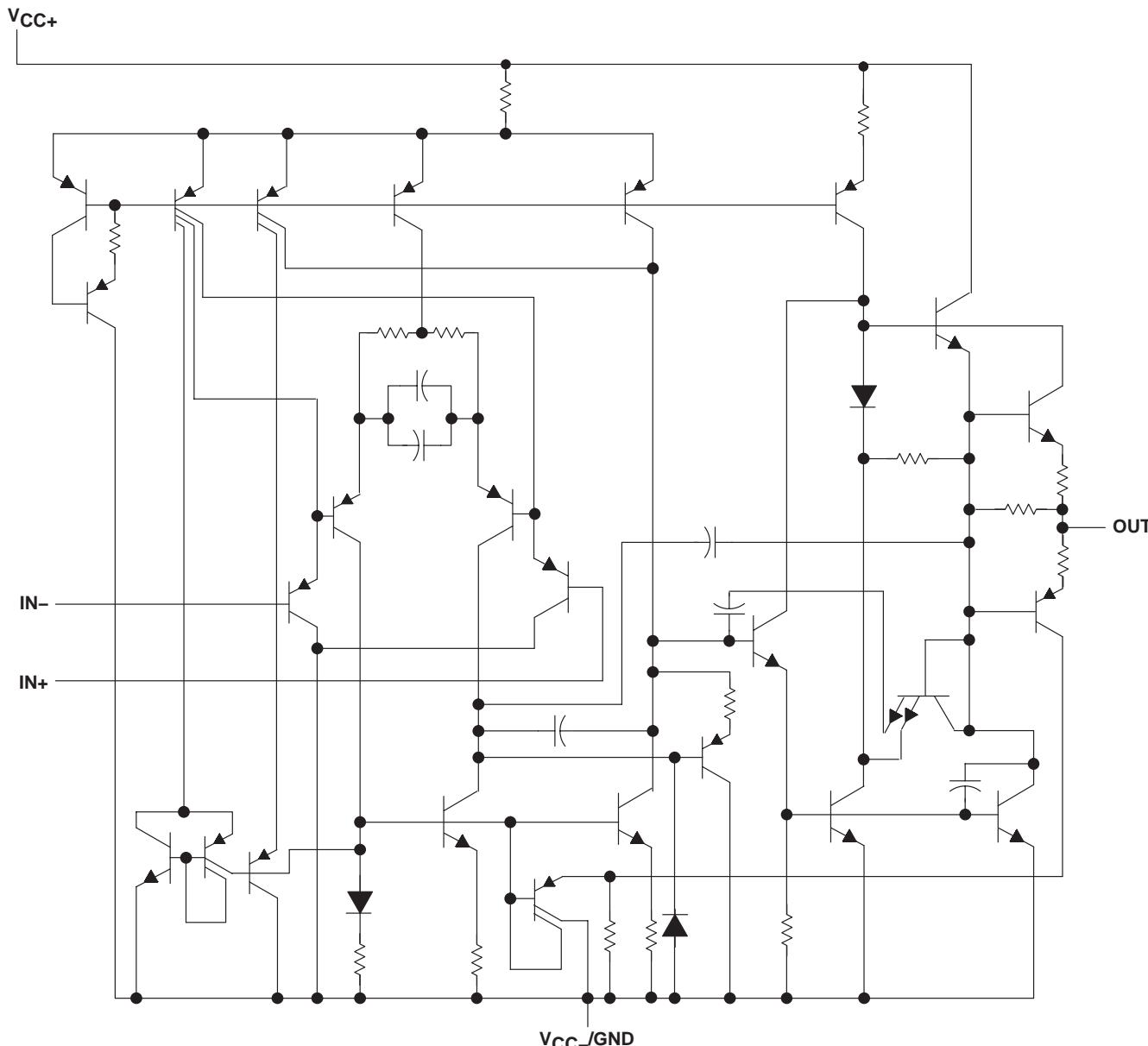
TL3474, TL3474A HIGH-SLEW-RATE, SINGLE-SUPPLY OPERATIONAL AMPLIFIERS

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description/ordering information (continued)

Quality, low-cost, bipolar fabrication with innovative design concepts is employed for the TL3474, TL3474A operational amplifiers. These devices offer 4 MHz of gain-bandwidth product, 13-V/ μ s slew rate, and fast settling time without the use of JFET device technology. Although the TL3474 and TL3474A can be operated from split supplies, they are particularly suited for single-supply operation because the common-mode input voltage range includes ground potential (V_{CC-}). With a Darlington transistor input stage, these devices exhibit high input resistance, low input offset voltage, and high gain. The all-npn output stage, characterized by no dead-band crossover distortion and large output voltage swing, provides high-capacitance drive capability, excellent phase and gain margins, low open-loop high-frequency output impedance, and symmetrical source/sink ac frequency response. These low-cost amplifiers are an alternative to the MC34074/A and MC33074/A operational amplifiers.

schematic (each amplifier)



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TL3474, TL3474A
HIGH-SLEW-RATE, SINGLE-SUPPLY OPERATIONAL AMPLIFIERS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage: V_{CC+} (see Note 1)	18 V
V_{CC-}	-18 V
Differential input voltage, V_{ID} (see Note 2)	±36 V
Input voltage, V_I (any input)	$V_{CC\pm}$
Input current, I_I (each input)	±1 mA
Output current, I_O	±80 mA
Total current into V_{CC+}	80 mA
Total current out of V_{CC-}	80 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	Unlimited
Package thermal impedance, θ_{JA} (see Notes 4 and 5): D package	86°C/W
N package	80°C/W
PW package	113°C/W
Operating virtual junction temperature, T_J	150°C
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T_{stg}	-65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}/GND .
 2. Differential voltages are at the noninverting input with respect to the inverting input. Excessive input current can flow when the input is less than $V_{CC-} - 0.3$ V.
 3. The output can be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.
 4. Maximum power dissipation is a function of $T_J(\max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

			MIN	MAX	UNIT
$V_{CC\pm}$	Supply voltage		4	36	V
V_{IC}	Common-mode input voltage	$V_{CC} = 5$ V	0	2.8	V
		$V_{CC\pm} = \pm 15$ V	-15	12.8	
T_A	Operating free-air temperature	TL3474C, TL3474AC	0	70	°C
		TL3474I, TL3474AI	-40	105	



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TL3474, TL3474A HIGH-SLEW-RATE, SINGLE-SUPPLY OPERATIONAL AMPLIFIERS

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electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TA	TL3474			TL3474A			UNIT	
			MIN	TYP†	MAX	MIN	TYP†	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	$V_{CC} = 5$ V	25°C	1.5	10	1.5	3	3	mV	
		$V_{CC} = \pm 15$ V	25°C	1.0	10	1.0	3	3		
		Full range‡		12			5	5		
αV_{IO} Temperature coefficient of input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	$V_{CC} = \pm 15$ V	Full range‡		10		10	10	$\mu V/^\circ C$	
I_{IO} Input offset current		$V_{CC} = \pm 15$ V	25°C	6	75	6	75	75	nA	
		Full range‡		300			300	300		
I_{IB} Input bias current	$V_{CC} = \pm 15$ V	25°C	100	500	100	500	500	500	nA	
		Full range‡		700			700	700		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	-15 to 12.8		-15 to 12.8		-15 to 12.8	-15 to 12.8	V	
		Full range‡	-15 to 12.8		-15 to 12.8		-15 to 12.8	-15 to 12.8		
V_{OH} High-level output voltage	$V_{CC+} = 5$ V, $V_{CC-} = 0$, $R_L = 2 \text{ k}\Omega$	25°C	3.7	4	3.7	4	4	4	V	
	$R_L = 10 \text{ k}\Omega$	25°C	13.6	14	13.6	14	14	14		
	$R_L = 2 \text{ k}\Omega$	Full range‡	13.4		13.4		13.4	13.4		
V_{OL} Low-level output voltage	$V_{CC+} = 5$ V, $V_{CC-} = 0$, $R_L = 2 \text{ k}\Omega$	25°C	0.1	0.3	0.1	0.3	0.1	0.3	V	
	$R_L = 10 \text{ k}\Omega$	25°C	-14.7	-14.3	-14.7	-14.3	-14.7	-14.3		
	$R_L = 2 \text{ k}\Omega$	Full range‡		-13.5			-13.5	-13.5		
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 2 \text{ k}\Omega$	25°C	25	100	25	100	25	100	V/mV	
		Full range‡	20		20		20	20		
I_{OS} Short-circuit output current	Source: $V_{ID} = 1$ V, $V_O = 0$	25°C	-10	-34	-10	-34	-10	-34	mA	
	Sink: $V_{ID} = -1$ V, $V_O = 0$		20	27	20	27	20	27		
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR}(\text{min})$, $R_S = 50 \Omega$	25°C	65	97	80	97	80	97	dB	
kSVR Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 13.5$ V to ± 16.5 V, $R_S = 100 \Omega$	25°C	70	97	70	97	70	97	dB	
I_{CC} Supply current (per channel)	$V_O = 0$, No load	25°C	3.5	4.5	3.5	4.5	3.5	4.5	mA	
		Full range‡	4.5	5.5	4.5	5.5	4.5	5.5		
	$V_{CC+} = 5$ V, $V_O = 2.5$ V, $V_{CC-} = 0$, No load	25°C	3.5	4.5	3.5	4.5	3.5	4.5		

† All typical values are at $T_A = 25^\circ C$.

‡ Full range is $0^\circ C$ to $70^\circ C$ for the TL3474C, TL3474AC devices and $-40^\circ C$ to $105^\circ C$ for the TL3474I, TL3474AI devices.



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TL3474, TL3474A
HIGH-SLEW-RATE, SINGLE-SUPPLY OPERATIONAL AMPLIFIERS

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operating characteristics, $V_{CC\pm} = \pm 15$ V, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	TL3474			TL3474A			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_I = -10$ V to 10 V, $R_L = 2 \text{ k}\Omega$, $C_L = 300 \text{ pF}$	$A_V = 1$	8	10	8	10	$\text{V}/\mu\text{s}$
SR-	Negative slew rate		$A_V = -1$		13		13	
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%		1.1		1.1	μs
			To 0.01%		2.2		2.2	
V_n	Equivalent input noise voltage	$f = 1$ kHz,	$R_S = 100 \Omega$		49		49	$\text{nV}/\sqrt{\text{Hz}}$
I_n	Equivalent input noise current	$f = 1$ kHz			0.22		0.22	$\text{pA}/\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$V_O(\text{PP}) = 2$ V to 20 V, $R_L = 2 \text{ k}\Omega$, $A_{VD} = 10$, $f = 10$ kHz			0.02		0.02	%
GBW	Gain-bandwidth product	$f = 100$ kHz		3	4	3	4	MHz
BW	Power bandwidth	$V_O(\text{PP}) = 20$ V, $R_L = 2 \text{ k}\Omega$, $A_{VD} = 1$, THD = 5.0%			160		160	kHz
ϕ_m	Phase margin	$R_L = 2 \text{ k}\Omega$,	$C_L = 0$		70		70	deg
		$R_L = 2 \text{ k}\Omega$,	$C_L = 300 \text{ pF}$		50		50	
	Gain margin	$R_L = 2 \text{ k}\Omega$,	$C_L = 0$		12		12	dB
		$R_L = 2 \text{ k}\Omega$,	$C_L = 300 \text{ pF}$		4		4	
r_i	Differential input resistance	$V_{IC} = 0$			150		150	$M\Omega$
C_i	Input capacitance	$V_{IC} = 0$			2.5		2.5	pF
	Channel separation	$f = 10$ kHz			101		101	dB
z_o	Open-loop output impedance	$f = 1$ MHz,	$A_V = 1$		20		20	Ω

TL3474, TL3474A HIGH-SLEW-RATE, SINGLE-SUPPLY OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

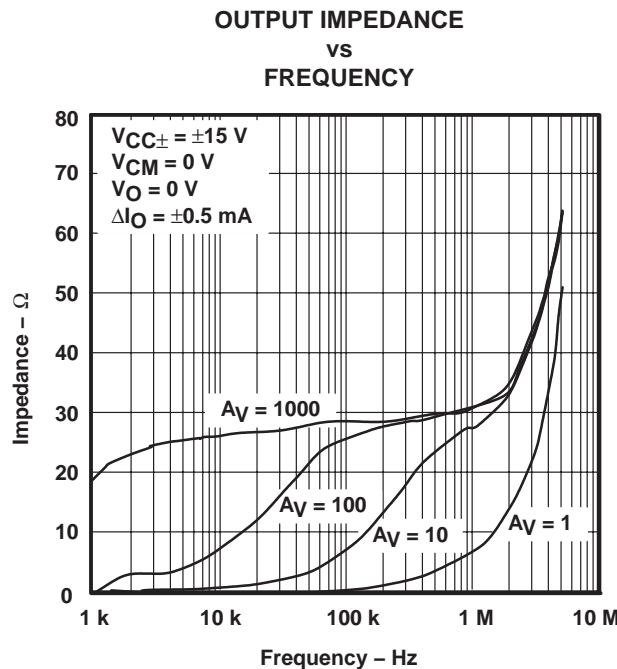


Figure 1

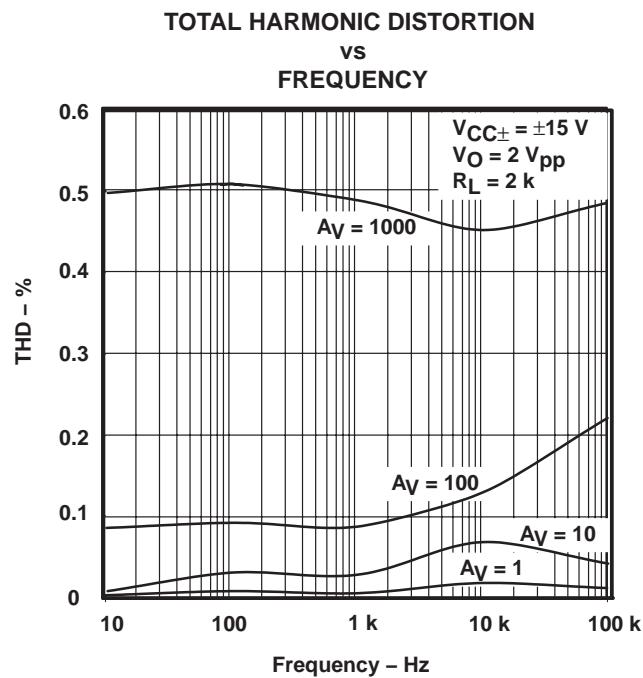


Figure 2

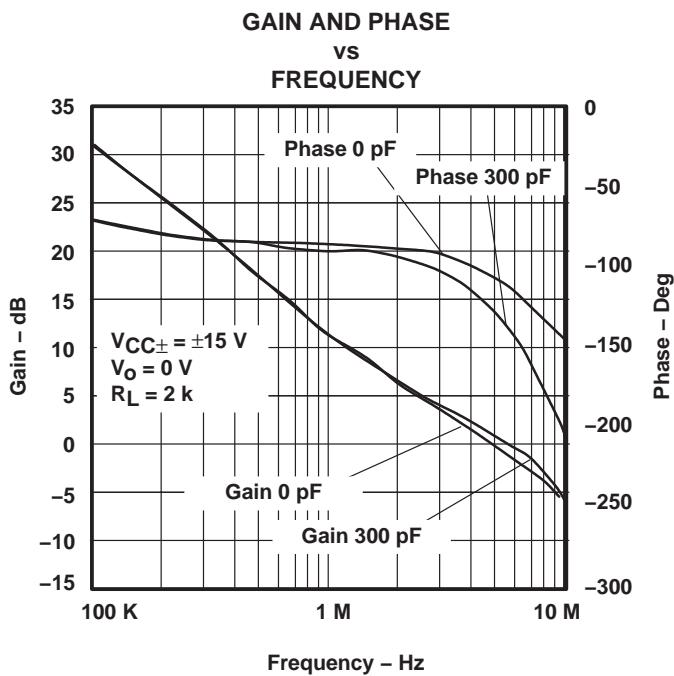


Figure 3

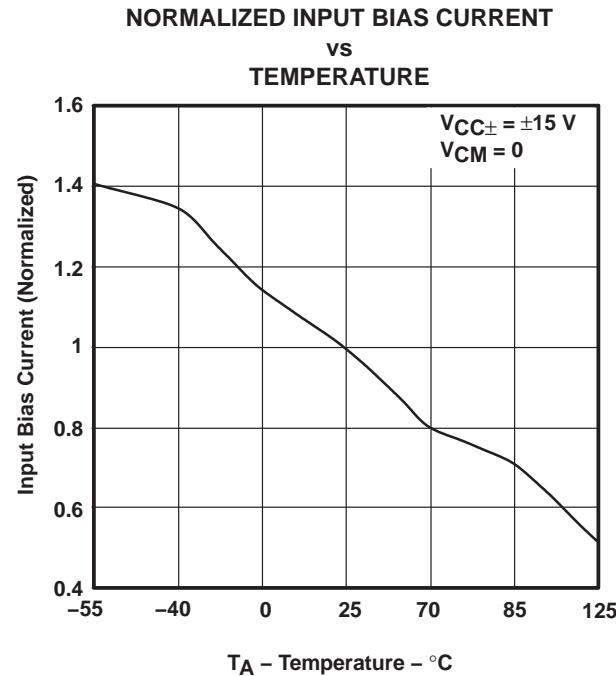


Figure 4

TL3474, TL3474A
HIGH-SLEW-RATE, SINGLE-SUPPLY OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

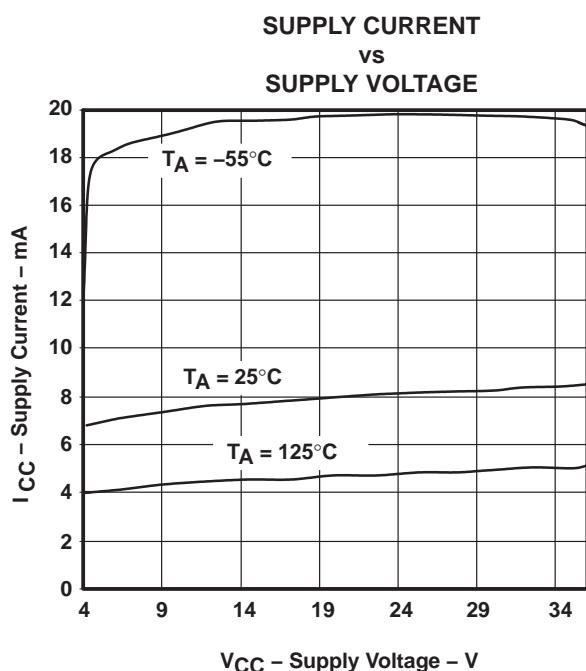


Figure 5

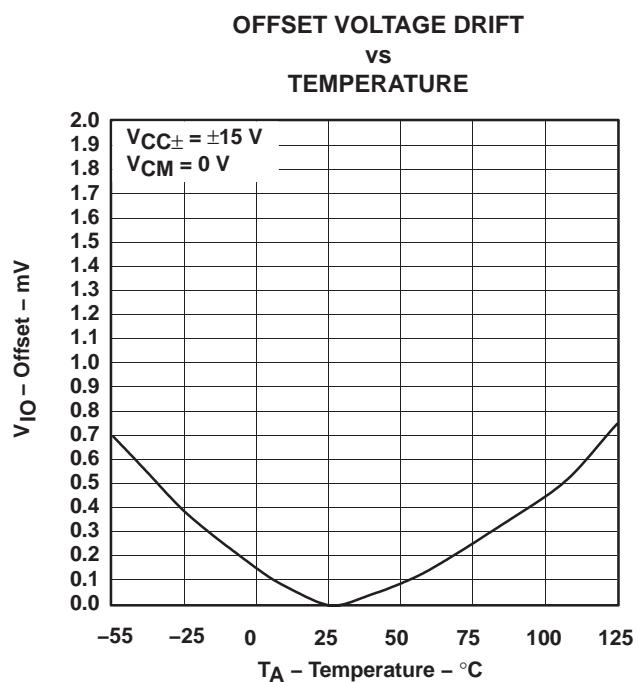


Figure 6

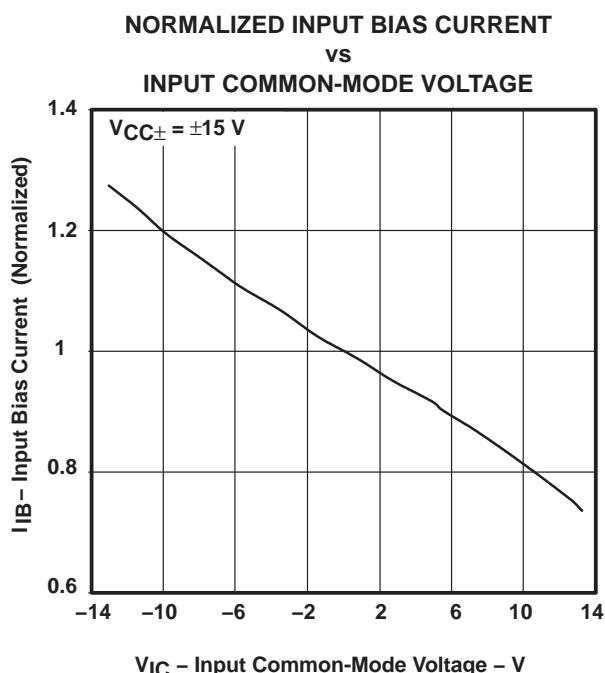


Figure 7

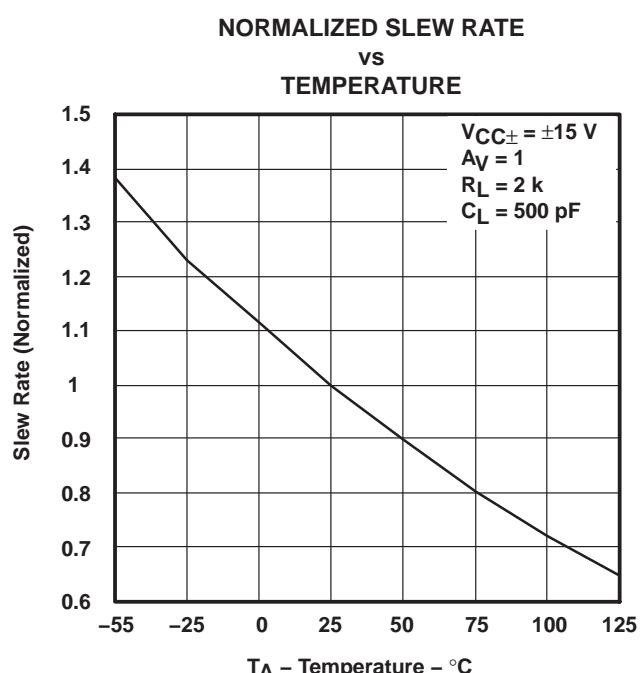


Figure 8

TL3474, TL3474A HIGH-SLEW-RATE, SINGLE-SUPPLY OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

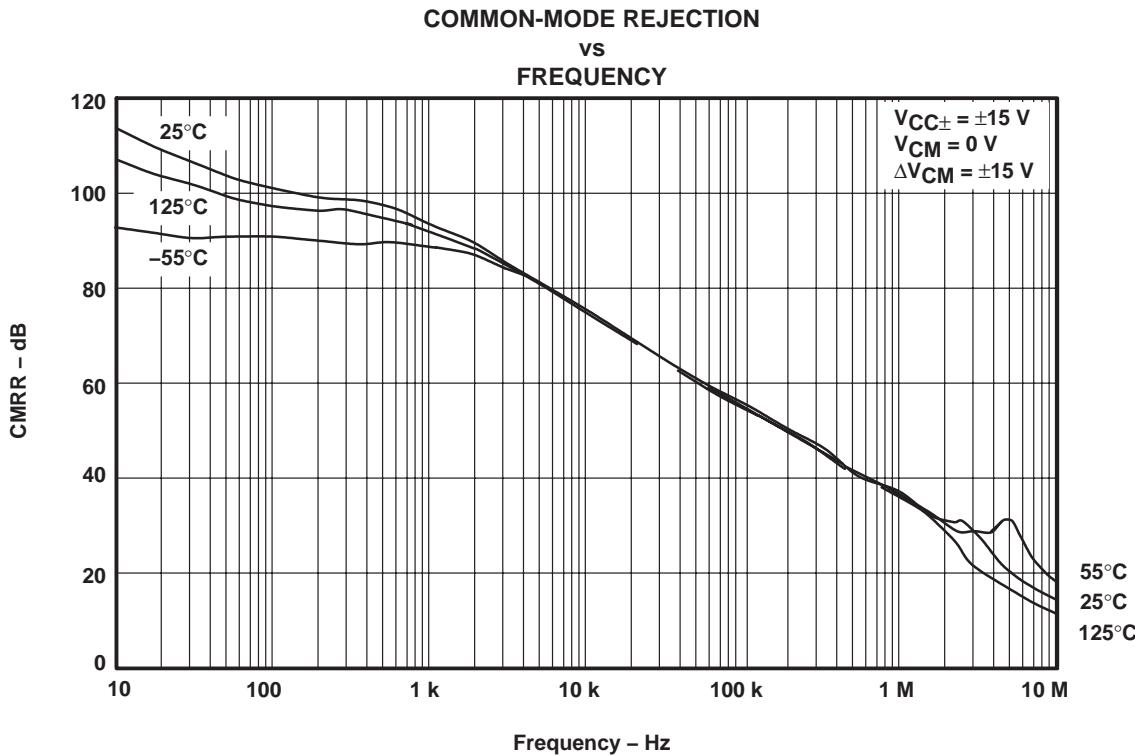


Figure 9

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TL3474ACDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3474A
TL3474ACDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3474A
TL3474ACN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL3474ACN
TL3474ACN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL3474ACN
TL3474ACPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T3474A
TL3474ACPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T3474A
TL3474AID	Obsolete	Production	SOIC (D) 14	-	-	Call TI	Call TI	-40 to 105	TL3474AI
TL3474AIDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TL3474AI
TL3474AIDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TL3474AI
TL3474AIDR.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	-	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TL3474AI
TL3474AIDRG4	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TL3474AI
TL3474AIDRG4.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TL3474AI
TL3474AIN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 105	TL3474AIN
TL3474AIN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 105	TL3474AIN
TL3474AIPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	Z3474A
TL3474AIPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	Z3474A
TL3474CD	Obsolete	Production	SOIC (D) 14	-	-	Call TI	Call TI	0 to 70	TL3474C
TL3474CDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3474C
TL3474CDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL3474C
TL3474CN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL3474CN
TL3474CN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL3474CN
TL3474CPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	0 to 70	T3474
TL3474CPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T3474
TL3474ID	Obsolete	Production	SOIC (D) 14	-	-	Call TI	Call TI	-40 to 105	TL3474I
TL3474IDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TL3474I
TL3474IDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TL3474I
TL3474IDR.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	-	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TL3474I
TL3474IN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 105	TL3474IN
TL3474IN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 105	TL3474IN

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TL3474IPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 105	Z3474
TL3474IPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	Z3474

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

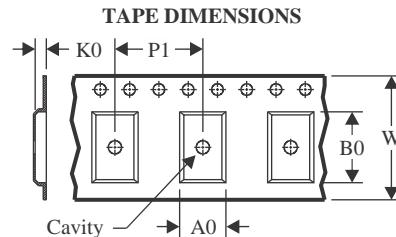
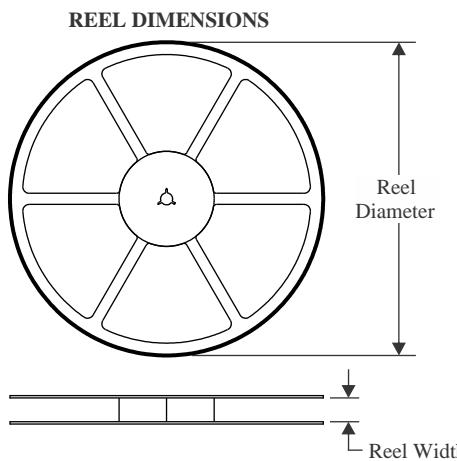
⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

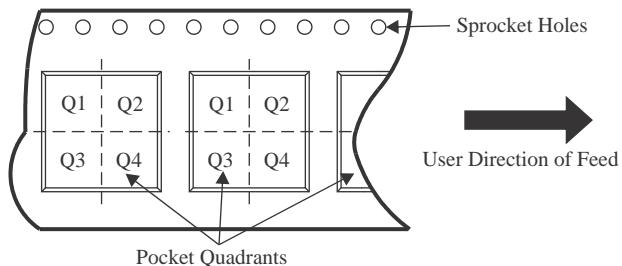
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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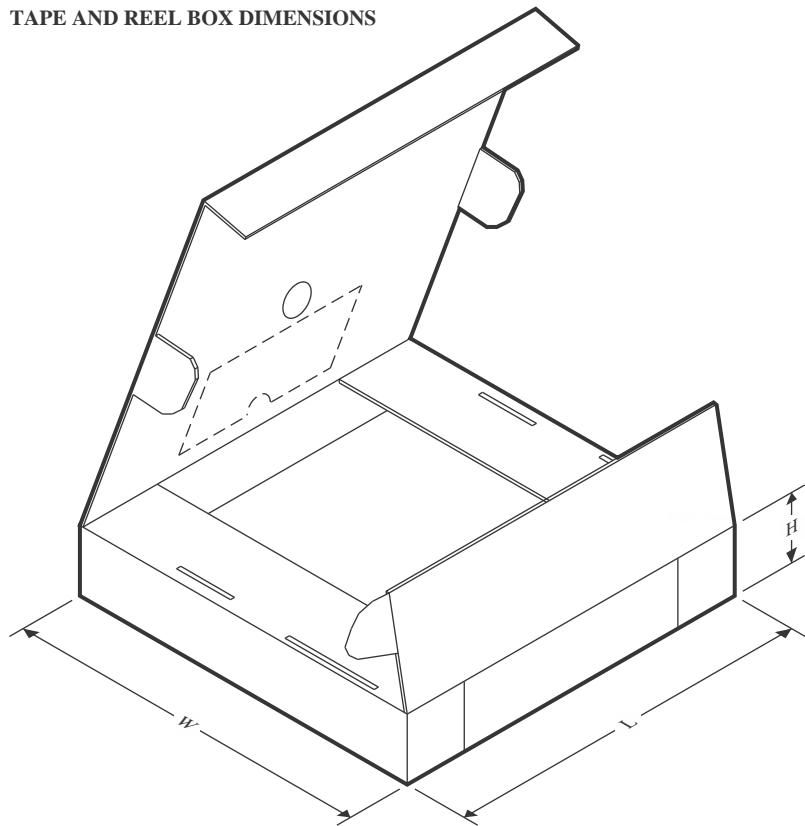
TAPE AND REEL INFORMATION

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

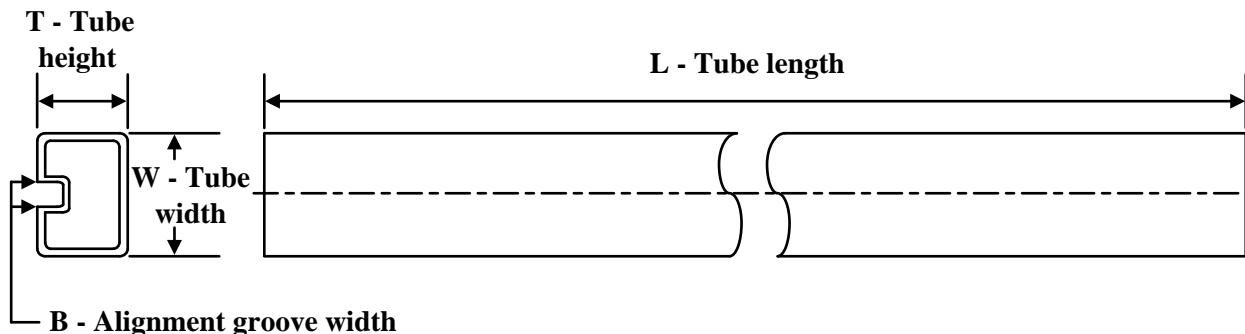
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL3474ACDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL3474ACPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL3474ACPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL3474AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL3474AIDRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL3474AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL3474AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL3474CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL3474CPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL3474IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL3474IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL3474ACDR	SOIC	D	14	2500	340.5	336.1	32.0
TL3474ACPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TL3474ACPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TL3474AIDR	SOIC	D	14	2500	353.0	353.0	32.0
TL3474AIDRG4	SOIC	D	14	2500	353.0	353.0	32.0
TL3474AIPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TL3474AIPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TL3474CDR	SOIC	D	14	2500	353.0	353.0	32.0
TL3474CPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
TL3474IDR	SOIC	D	14	2500	353.0	353.0	32.0
TL3474IPWR	TSSOP	PW	14	2000	356.0	356.0	35.0

TUBE


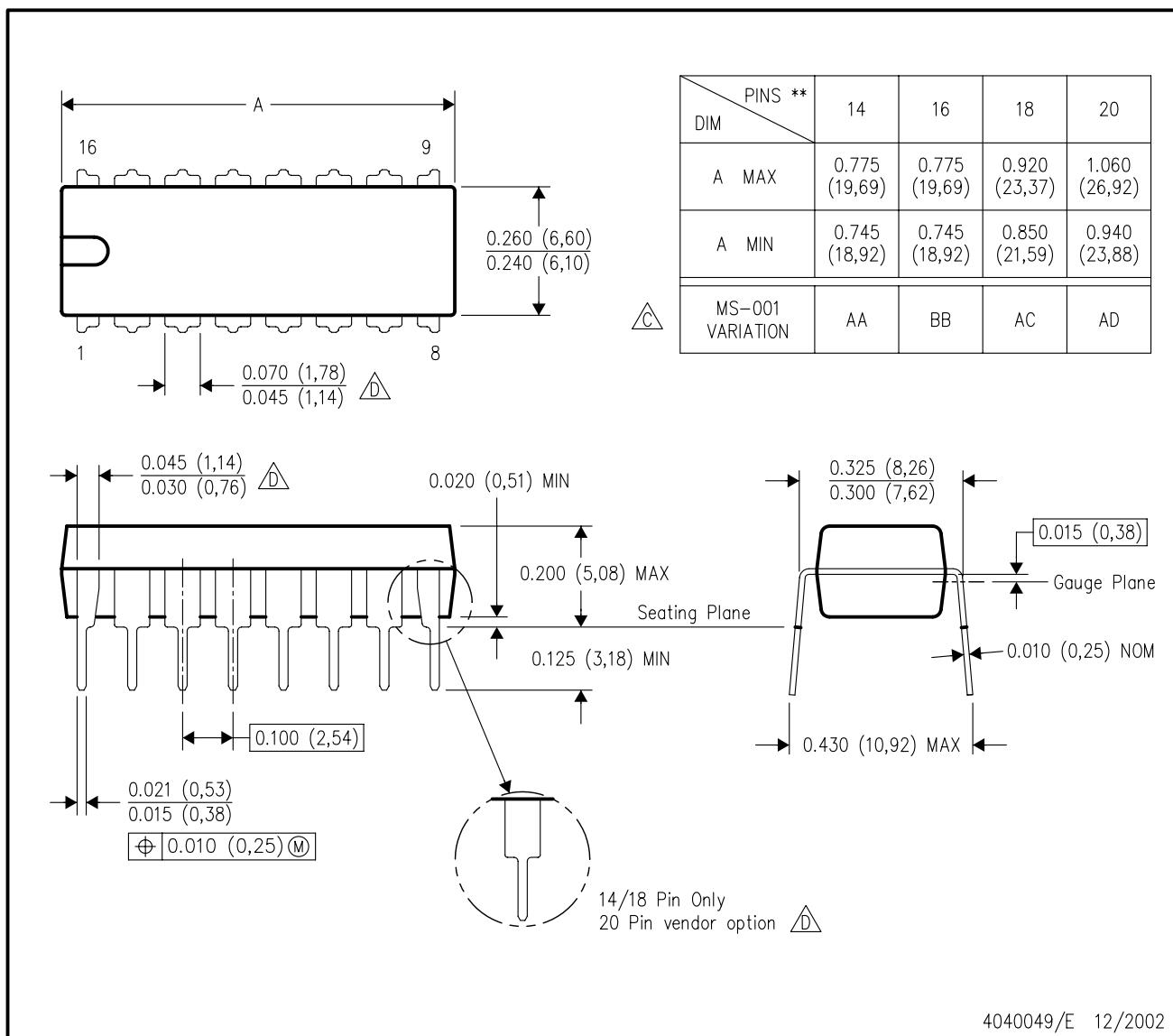
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μ m)	B (mm)
TL3474ACN	N	PDIP	14	25	506	13.97	11230	4.32
TL3474ACN.A	N	PDIP	14	25	506	13.97	11230	4.32
TL3474AIN	N	PDIP	14	25	506	13.97	11230	4.32
TL3474AIN.A	N	PDIP	14	25	506	13.97	11230	4.32
TL3474CN	N	PDIP	14	25	506	13.97	11230	4.32
TL3474CN.A	N	PDIP	14	25	506	13.97	11230	4.32
TL3474IN	N	PDIP	14	25	506	13.97	11230	4.32
TL3474IN.A	N	PDIP	14	25	506	13.97	11230	4.32

N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



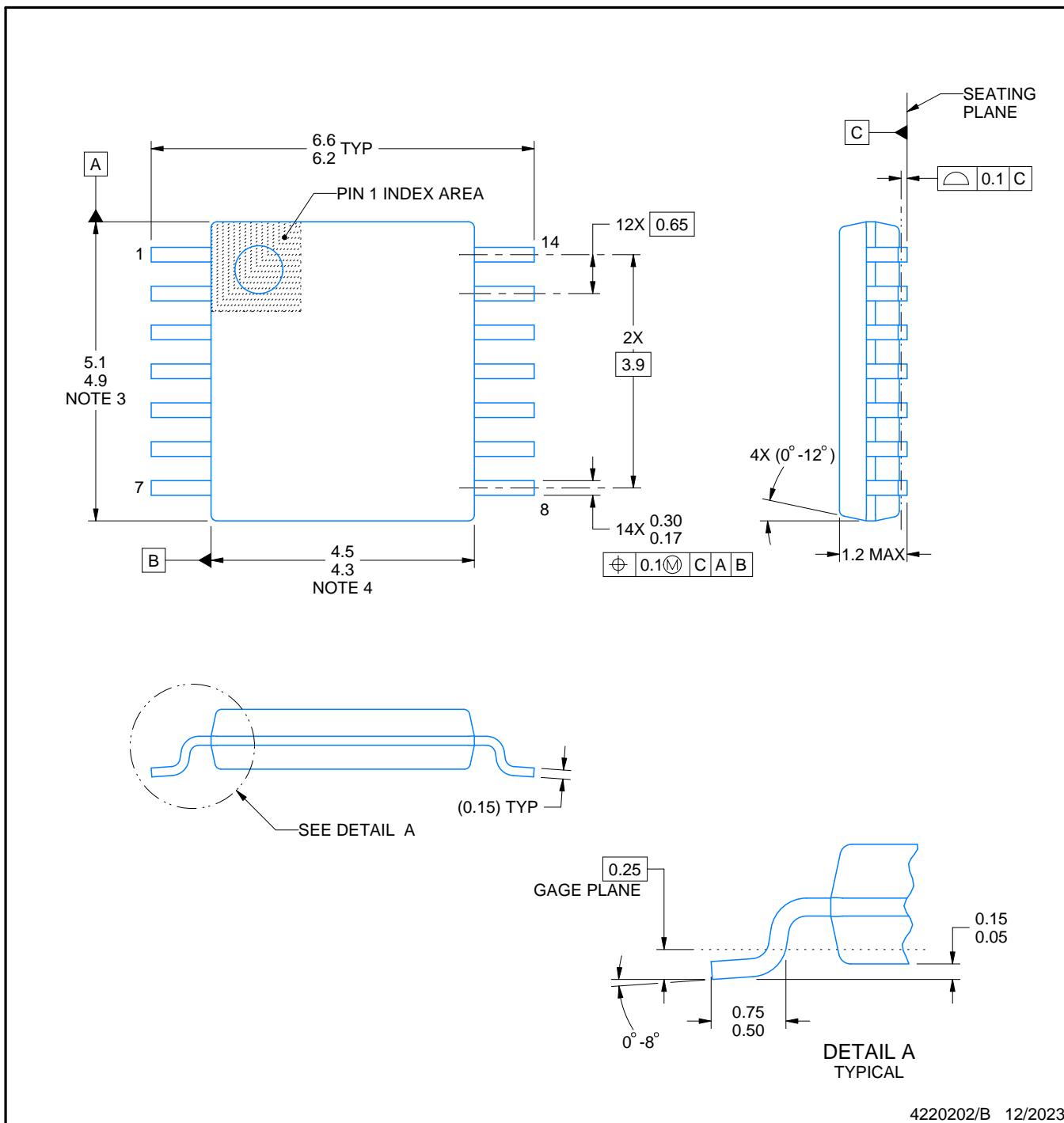
PACKAGE OUTLINE

PW0014A



TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

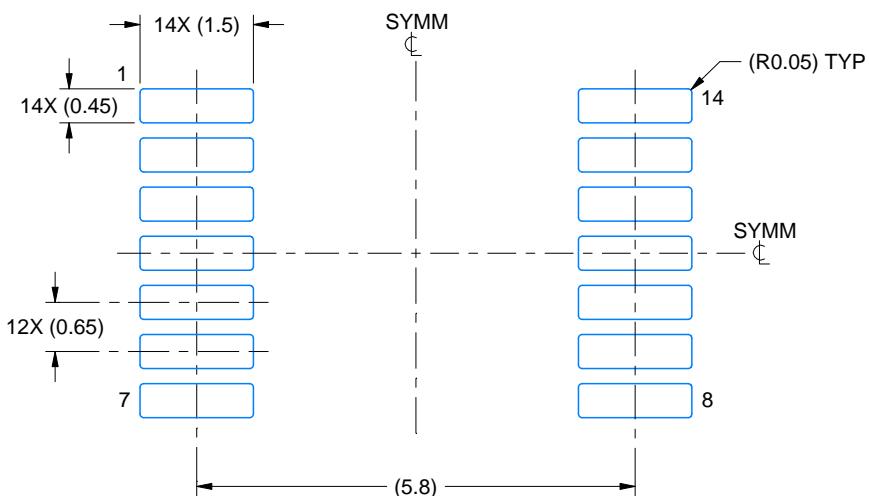
- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

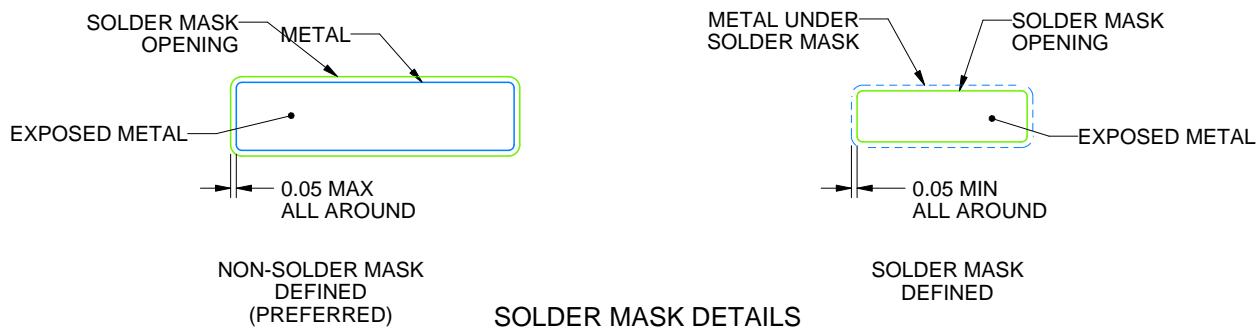
PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

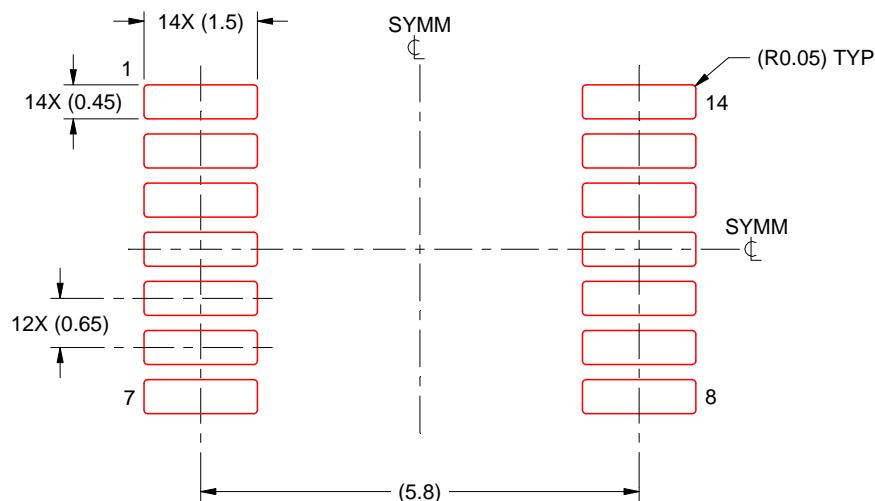
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

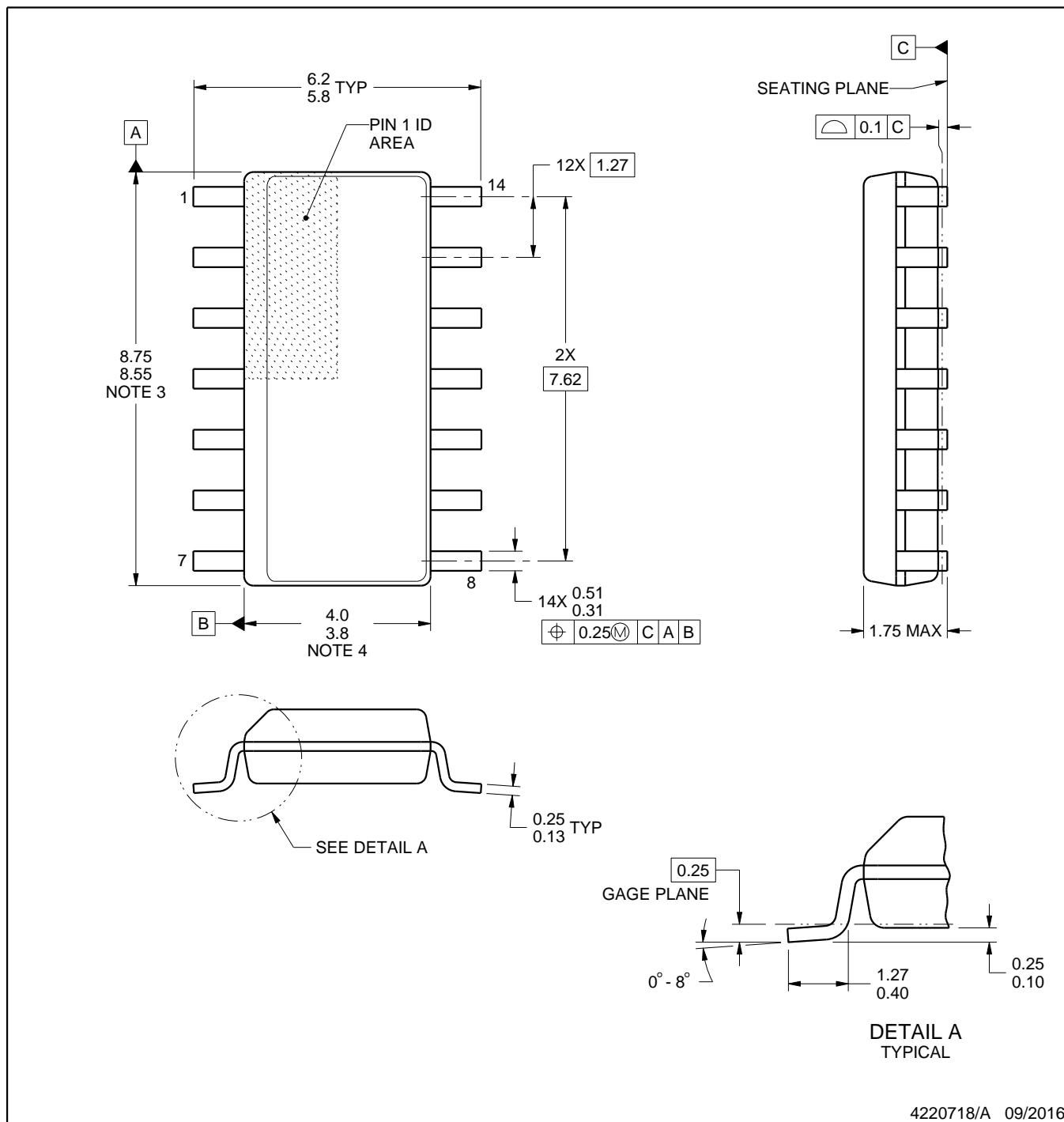
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

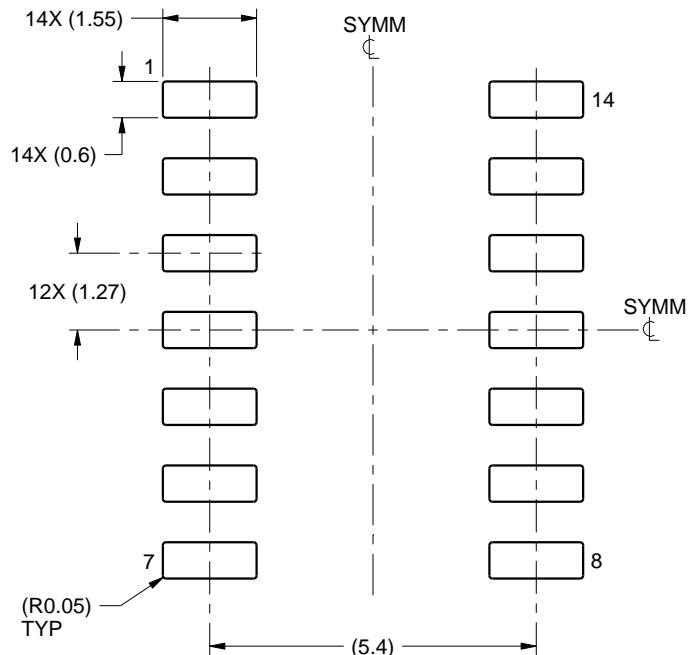
- All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- Reference JEDEC registration MS-012, variation AB.

EXAMPLE BOARD LAYOUT

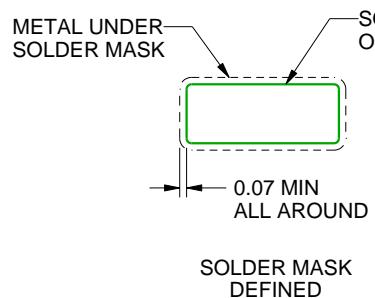
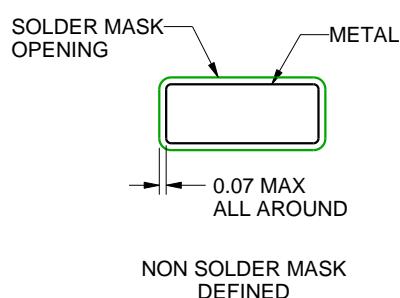
D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

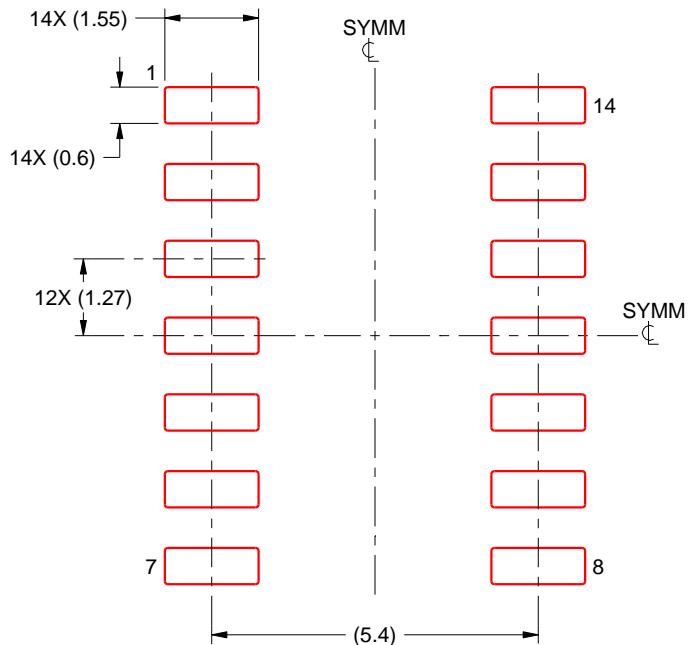
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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